

DTQ6011N06SJ www.din-tek.jp

N-Channel 60 V (D-S) Super Junction MOSFET

PRODUCT SUMMARY						
V _{DS} (V)	R _{DS(on)} (mΩ)(Typ.)	I _D (A)ª	Q _g (Typ.)			
60	0.86 at V _{GS} = 10 V	305	108 nC			

DFN5X6-8L Pin Configuration

FEATURES

- DT- SJ Power MOSFET
- + 100 $\%~{\rm R_g}$ and UIS Tested
- Low RDS(ON)

APPLICATIONS

· Motor and BMS

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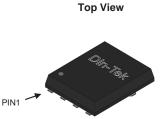
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G[4 Synchronous Rectification in DC/DC and AC/DC Converters.





N-Channel MOSFET

ABSOLUTE MAXIMUM RATINGS (T _C = 25 °C, unless otherwise noted)					
PARAMETER	SYMBOL	LIMIT	UNIT		
Drain-Source Voltage	V _{DS}	60	M		
Gate-Source Voltage	V _{GS}	± 20	V		
Continuous Drain Current (T _{.1} = 175 °C) ^a	T _C = 25 °C		305	A	
Continuous Drain Current $(1j = 175 C)^2$	T _C = 100 °C	– I _D	207		
Pulsed Drain Current ^b	I _{DM}	1052			
Single Avalanche Energy	E _{AS}	1040	mJ		
	T _C = 25 °C	P	268	W	
Maximum Power Dissipation ^c	T _C = 100 °C	– P _D –	134		
Operating Junction and Storage Temperature	Range	T _J , T _{stg}	- 55 to + 175	°C	

THERMAL RESISTANCE RATINGS					
PARAMETER	SYMBOL	LIMIT	UNIT		
Junction-to-Ambient (PCB Mount) ^d	R _{thJA}	45	°C/W		
Junction-to-Case (Drain)	R _{thJC}	0.56	0/11		

Notes

a. Calculated continuous current based on maximum allowablejunction temperature.

- b. Repetitive rating; pulse width limited by max. junction temperature.
- c. Pd is based on max. junction temperature, using junction-case thermal resistance.
- d. The value of ReJA is measured with the device mounted on 1 in 2 FR-4 board with 2oz. Copper, in a still air environment with Ta=25 °C.



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PARAMETER	SYMBOL TEST CONDITIONS		MIN.	TYP.	MAX.	UNIT	
Static							
Drain-Source Breakdown Voltage	V _{DS}	$V_{GS} = 0 V, I_D = 250 \mu A$ 60		-	-	V	
Gate Threshold Voltage	V _{GS(th)}	$V_{DS} = V_{GS}$, $I_D = 250 \ \mu A$	2	-	4	4 V	
Gate-Body Leakage	I _{GSS}	$V_{DS} = 0 V, V_{GS} = \pm 20 V$	-	-	± 100	nA	
		$V_{DS} = 60 \text{ V}, \text{ V}_{GS} = 0 \text{ V}$	-	-	1		
Zero Gate Voltage Drain Current	IDSS	V _{DS} = 48 V, V _{GS} = 0 V, T _J = 125 °C		-	100	μA	
On-State Drain Current ^a	I _{D(on)}	$V_{DS} \ge 5 \text{ V}, \text{ V}_{GS} = 10 \text{ V}$	305	-	-	А	
Drain-Source On-State Resistance ^a	R _{DS(on)}	$V_{GS} = 10 \text{ V}, \text{ I}_{D} = 20 \text{ A}$	-	0.86	1.1	mΩ	
Forward Transconductance a	g fs	$V_{DS} = 5 V, I_{D} = 20 A$	-	76	-	S	
Dynamic ^b				•	•		
Input Capacitance	C _{iss}		-	7204	-	pF	
Output Capacitance	C _{oss}	$V_{GS} = 0 V, V_{DS} = 30 V, f = 1 MHz$	-	3129	-		
Reverse Transfer Capacitance	C _{rss}		-	202	-		
Total Gate Charge ^c	Qg		-	108	-	nC	
Gate-Source Charge ^c	Q _{gs}	$V_{DS} = 30 \text{ V}, V_{GS} = 10 \text{ V}, I_D = 20 \text{ A}$	-	26	-		
Gate-Drain Charge ^c	Q _{gd}		-	24	-		
Gate Resistance	R _g f = 1 MHz		-	2.4	-	Ω	
Turn-On Delay Time ^c	t _{d(on)}		-	28	-		
Rise Time ^c	tr	$V_{DD} = 30 \text{ V}, \text{ I}_{D} = 20 \text{ A}, \text{ R}_{q} = 3 \Omega$	-	45	-		
Turn-Off Delay Time ^c	t _{d(off)}	V _{GS} = 10 V	-	73	-	ns	
Fall Time ^c	t _f		-	95	-		
Drain-Source Body Diode Ratings and	Characterist	ics ^b (T _C = 25 °C)					
Continuous Source-Drain Diode Current	۱ _S	T _C = 25 °C	-	-	305	А	
Pulsed Current	I _{SM}		-	-	1052	А	
Forward Voltage ^a	V _{SD}	$I_{F} = 2A, V_{GS} = 0 V$	-	0.7	1.2	V	
Reverse Recovery Time	t _{rr}		-	73	-	ns	
Reverse Recovery Charge	Q _{rr}	$I_{F} = 20 \text{ A}, \text{ di/dt} = 100 \text{ A/}\mu\text{s}$	-	95	-	nC	

Notes

a. Pulse test; pulse width \leq 300 µs, duty cycle \leq 2 %.

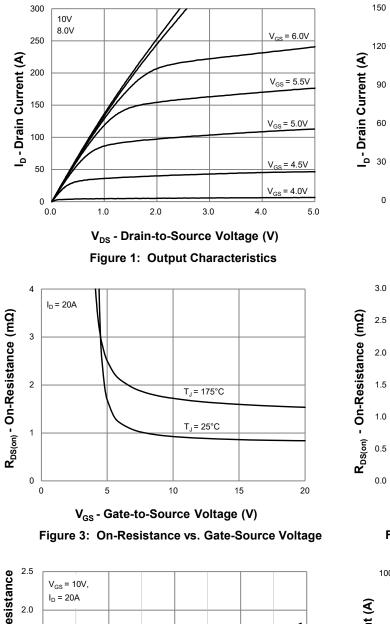
b. Guaranteed by design, not subject to production testing.

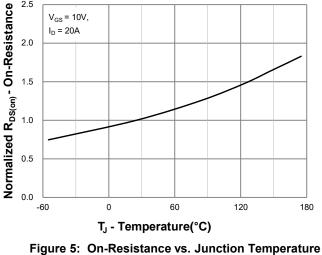
c. Independent of operating temperature.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those in dicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended pe riods may affect device reliability.



TYPICAL CHARAC TERISTICS (25 °C, unless otherwise noted)





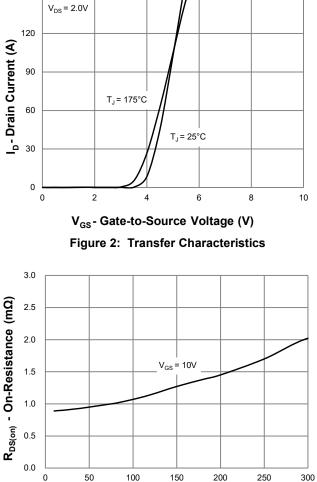
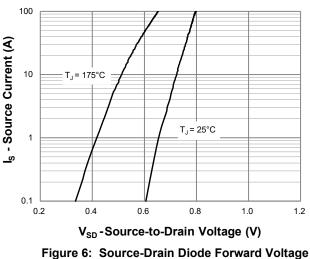


Figure 4: On-Resistance vs. Gate-Source Voltage

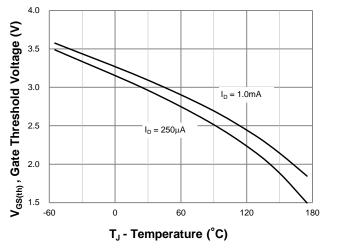
I_D- Drain Current (A)



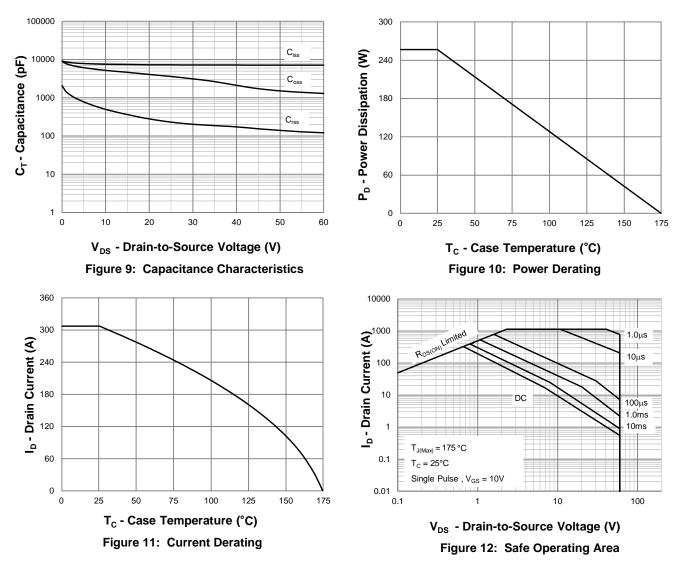


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TYPICAL CHARAC TERISTICS (25 °C, unless otherwise noted)







V_{GS} - Gate-to-Source Voltage (V)

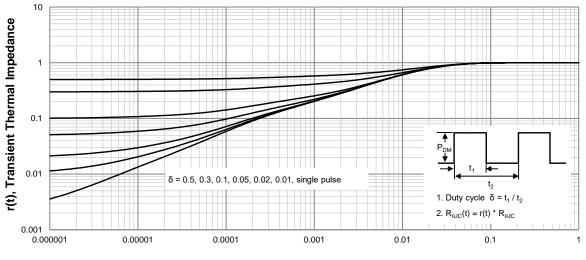
Figure8: Gate Charge Characteristics

Q_g - Total Gate Charge (nC)

I_D = 20A



TYPICAL CHARAC TERISTICS (25 °C, unless otherwise noted)

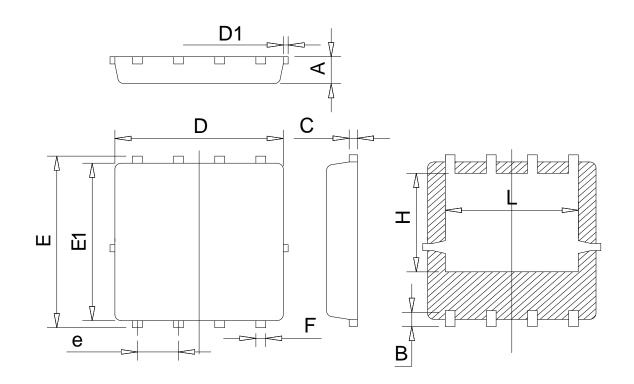


Pulse Width (s)

Figure 13: Normalized Maximum Transient Thermal Impedance



DFN5X6-8L PACKAGE OUTLINE



COMMON DIMENSIONS (UNITS OF MEASURE=MILLIMETER)

Symbol	Min	Тур	Max
A	0.78	0.95	1.12
В	0.45	0.58	0.78
С	0.18	0.254	0.36
D	4.70	5.20	5.45
D1			0.18
E	5.85	6.05	6.25
E1	5.38	5.55	5.98
е	1.15	1.27	1.40
F	0.18	0.30	0.52
Н	3.25	3.47	3.70
L	3.75	4.00	4.25



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